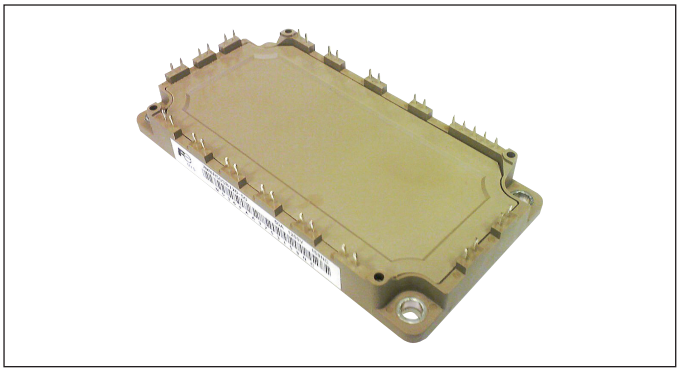
7MBR75VB120-50

IGBT Modules

IGBT MODULE (V series)
1200V / 75A / PIM

Features

Low V_{CE}(sat)
Compact Package
P.C.Board Mount Module
Converter Diode Bridge Dynamic Brake Circuit
RoHS compliant product



Applications

Inverter for Motor Drive
AC and DC Servo Drive Amplifier
Uninterruptible Power Supply

Maximum Ratings and Characteristics

● **Absolute Maximum Ratings (at T_c=25°C unless otherwise specified)**

Items		Symbols	Conditions		Maximum ratings	Units
Inverter	Collector-Emitter voltage	V_{CES}			1200	V
	Gate-Emitter voltage	V_{GES}			±20	V
	Collector current	I_C	Continuous	T_c=100°C	75	A
		I_{cp}	1ms	T_c=80°C	150	
		$-I_C$			75	
		$-I_{C\ pulse}$	1ms		150	
	Collector power dissipation	P_C	1 device		385	W
Brake	Collector-Emitter voltage	V_{CES}			1200	V
	Gate-Emitter voltage	V_{GES}			±20	V
	Collector current	I_C	Continuous	T_c=80°C	50	A
		I_{CP}	1ms	T_c=80°C	100	
	Collector power dissipation	P_C	1 device		280	W
	Repetitive peak reverse voltage (Diode)	V_{RRM}			1200	V
Converter	Repetitive peak reverse voltage	V_{RRM}			1600	V
	Average output current	I_O	50Hz/60Hz, sine wave		75	A
	Surge current (Non-Repetitive)	I_{FSM}	10ms, T_j=150°C half sine wave		520	A
	I^2t (Non-Repetitive)	I^2t			1352	A^2s
Junction temperature		T_j	Inverter, Brake		175	°C
			Converter		150	
Operating junciton temperature (under switching conditions)		T_{jop}	Inverter, Brake		150	
			Converter		150	
Case temperature		T_C			125	
Maximum junction temperature		T_{jmax}			175	
Operating temperature (under switching conditions)		T_{jop}			150	
Storage temperature		T_{stg}			-40 ~ +125	
Isolation voltage	between terminal and copper base (*1) between thermistor and others (*2)	V_{iso}	AC : 1min.		2500	VAC
Screw torque	Mounting (*3)	-	M5		3.5	N m

Note *1: All terminals should be connected together during the test.
Note *2: Two thermistor terminals should be connected together, other terminals should be connected together and shorted to base plate during the test.
Note *3: Recommendable value : 2.5-3.5 Nm (M5)

● Electrical characteristics (at T_j= 25°C unless otherwise specified)

Items		Symbols	Conditions		Characteristics min.	Characteristics typ.	Characteristics max.	Units
Inverter	Zero gate voltage collector current	I_{CES}	V_{GE} = 0V, V_{CE} = 1200V		-	-	1.0	mA
	Gate-Emitter leakage current	I_{GES}	V_{GE} = 0V, V_{GE} = ±20V		-	-	200	nA
	Gate-Emitter threshold voltage	$V_{GE\ (th)}$	V_{CE} = 20V, I_C = 75mA		6.0	6.5	7.0	V
	Collector-Emitter saturation voltage	$V_{CE\ (sat)}$ (terminal)	V_{GE} = 15V, I_C = 75A	T_j=25°C	-	2.35	2.80	V
				T_j=125°C	-	2.70	-	
				T_j=150°C	-	2.75	-	
		$V_{CE\ (sat)}$ (chip)	V_{GE} = 15V, I_C = 75A	T_j=25°C	-	1.85	2.30	
				T_j=125°C	-	2.20	-	
				T_j=150°C	-	2.25	-	
	Internal gate resistance	Rg(int)	-		-	10	-	Ω
	Input capacitance	C_{ies}	V_{CE} = 10V, V_{GE} = 0V, f = 1MHz		-	6.0	-	nF
	Turn-on time	t_{on}	V_{CC} = 600V, I_C = 75A, V_{GE} = +15 / -15V, R_G = 2.2Ω		-	0.39	1.20	μs
		t_r			-	0.09	0.60	
		$t_{r\ (i)}$			-	0.03	-	
	Turn-off time	t_{off}			-	0.53	1.00	
		t_f			-	0.06	0.30	
	Forward on voltage	V_F (terminal)	I_F = 75A	T_j=25°C	-	2.20	2.65	V
				T_j=125°C	-	2.35	-	
				T_j=150°C	-	2.30	-	
		V_F (chip)	I_F = 75A	T_j=25°C	-	1.70	2.15	
				T_j=125°C	-	1.85	-	
				T_j=150°C	-	1.80	-	
	Reverse recovery time	t_{rr}	I_F = 75A		-	-	0.35	μs
Brake	Zero gate voltage collector current	I_{CES}	V_{GE} = 0V, V_{CE} = 1200V		-	-	1.0	mA
	Gate-Emitter leakage current	I_{GES}	V_{CE} = 0V, V_{GE} = +20 / -20V		-	-	200	nA
	Collector-Emitter saturation voltage	$V_{CE\ (sat)}$ (terminal)	V_{GE} = 15V, I_C = 50A	T_j=25°C	-	2.20	2.65	V
				T_j=125°C	-	2.55	-	
				T_j=150°C	-	2.60	-	
		$V_{CE\ (sat)}$ (chip)	V_{GE} = 15V, I_C = 50A	T_j=25°C	-	1.85	2.30	
				T_j=125°C	-	2.20	-	
				T_j=150°C	-	2.25	-	
	Internal gate resistance	Rg(int)	-		-	4	-	Ω
	Turn-on time	t_{on}	V_{CE} = 600V, I_C = 50A, V_{GE} = +15 / -15V, R_G = 15Ω		-	0.39	1.20	μs
		t_r			-	0.09	0.60	
	Turn-off time	t_{off}			-	0.53	1.00	
		t_f			-	0.06	0.30	
	Reverse current	I_{RRM}	V_R = 1200V		-	-	1.00	mA
Converter	Forward on voltage	V_{FM} (chip)	I_F = 75A	terminal	-	1.90	2.35	V
				chip	-	1.40	-	
	Reverse current	I_{RRM}	V_R = 1600V		-	-	1.0	mA
Thermistor	Resistance	R	T = 25°C		-	5000	-	Ω
			T = 100°C		465	495	520	
	B value	B	T = 25 / 50°C		3305	3375	3450	K

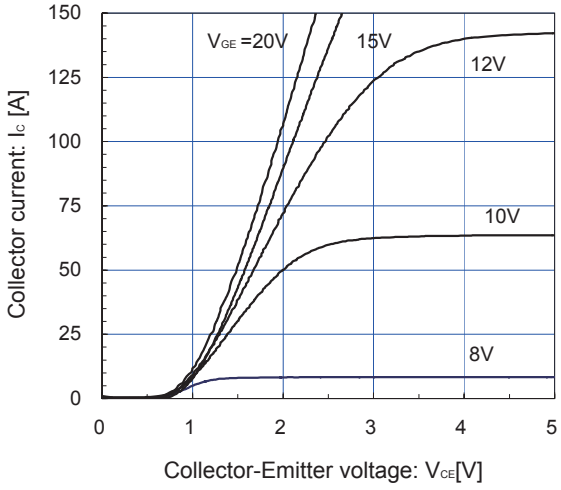
● Thermal resistance characteristics

Items	Symbols	Conditions	Characteristics min.	Characteristics typ.	Characteristics max.	Units
Thermal resistance (1device)	$R_{th(j-c)}$	Inverter IGBT	-	-	0.39	°C/W
		Inverter FWD	-	-	0.55	
		Brake IGBT	-	-	0.54	
		Converter Diode	-	-	0.43	
Contact thermal resistance (1device) (*4)	$R_{th(c-f)}$	with Thermal Compound	-	0.05	-	

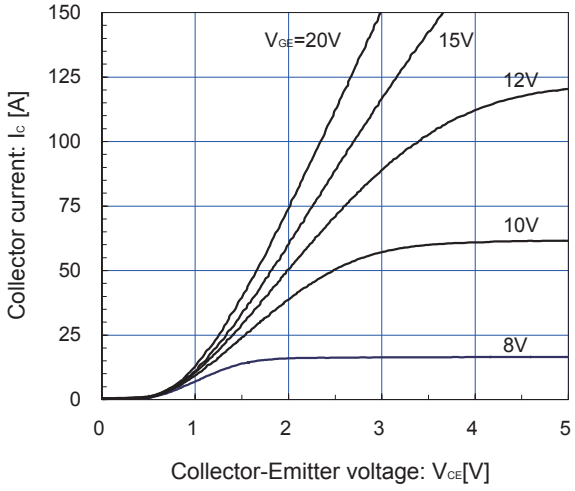
Note *4: This is the value which is defined mounting on the additional cooling fin with thermal compound.

■ Characteristics (Representative)

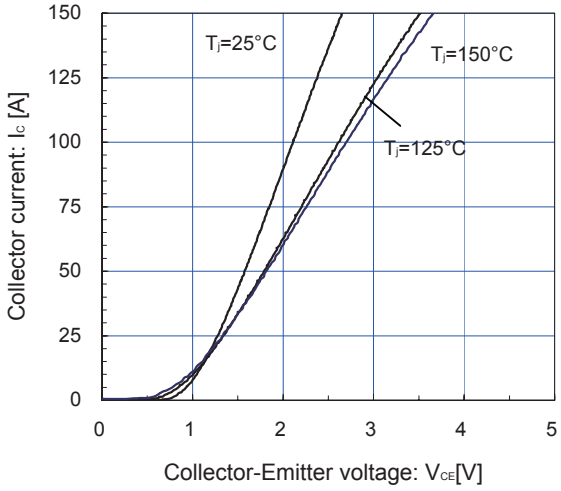
[Inverter]
Collector current vs. Collector-Emitter voltage (typ.)
T_j= 25°C / chip



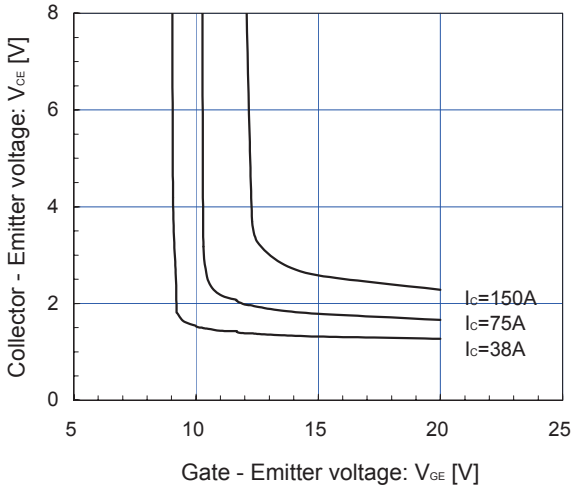
[Inverter]
Collector current vs. Collector-Emitter voltage (typ.)
T_j= 150°C / chip



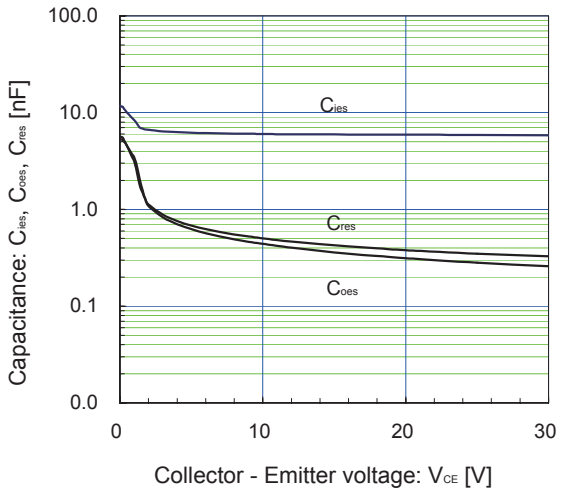
[Inverter]
Collector current vs. Collector-Emitter voltage (typ.)
V_{GE}=15V / chip



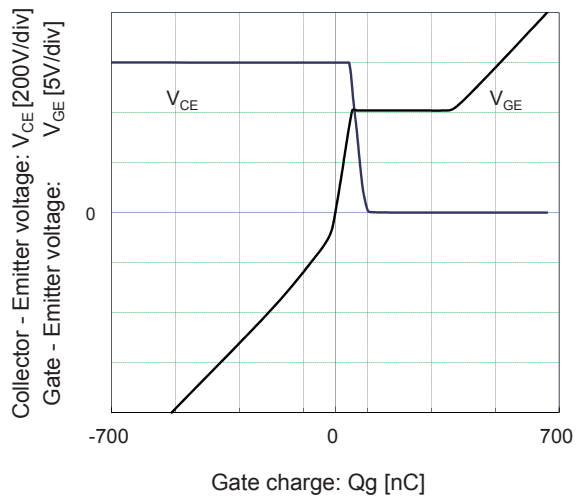
[Inverter]
Collector-Emitter voltage vs. Gate-Emitter voltage (typ.)
T_j= 25°C / chip



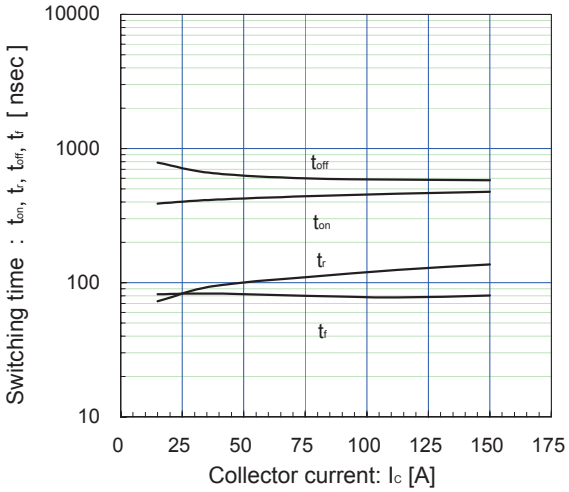
[Inverter]
Capacitance vs. Collector-Emitter voltage (typ.)
V_{GE}=0V, f= 1MHz, T_j= 25°C



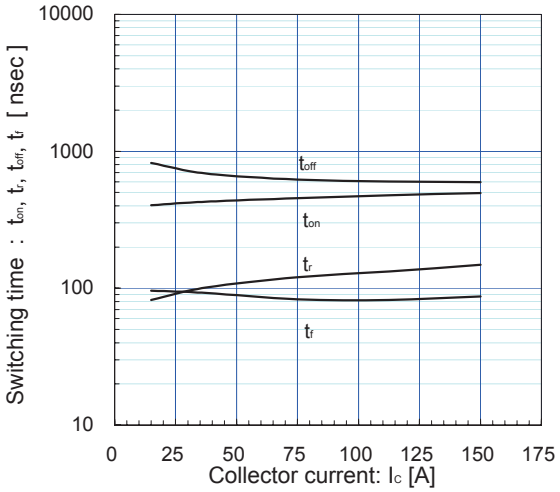
[Inverter]
Dynamic gate charge (typ.)
Vcc=600V, Ic=75A, Tj= 25°C



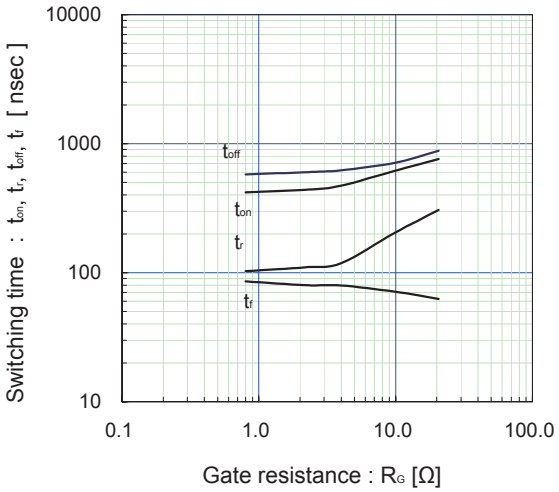
[Inverter]
Switching time vs. Collector current (typ.)
V_{CC}=600V, V_{GE}=±15V, R_G=2.2Ω, T_j= 125°C



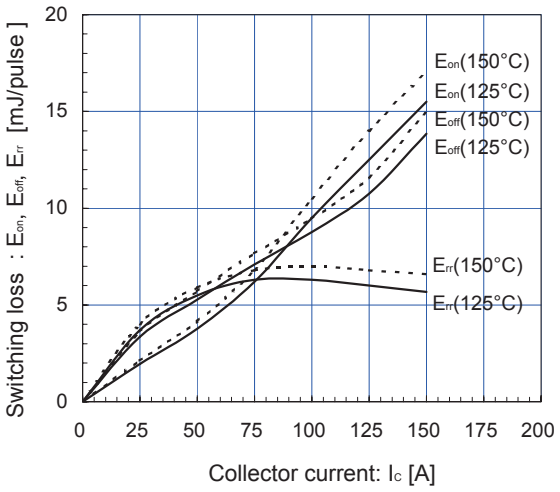
[Inverter]
Switching time vs. Collector current (typ.)
V_{CC}=600V, V_{GE}=±15V, R_G=2.2Ω, T_j= 150°C



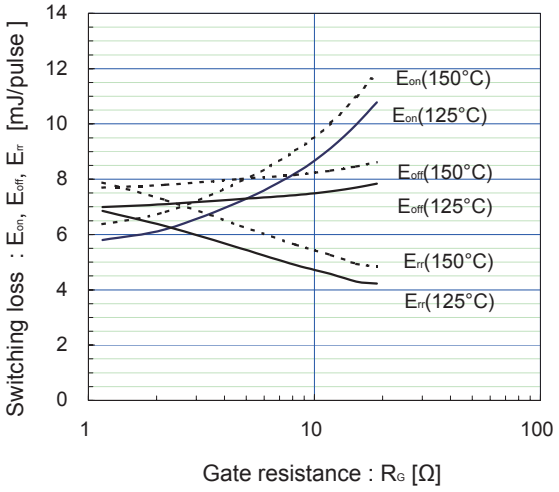
[Inverter]
Switching time vs. gate resistance (typ.)
V_{CC}=600V, I_C=75A, V_{GE}=±15V, T_j= 125°C



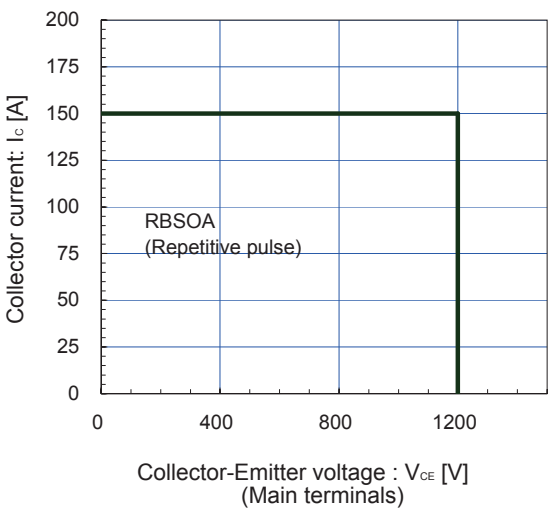
[Inverter]
Switching loss vs. Collector current (typ.)
V_{CC}=600V, V_{GE}=±15V, R_G=2.2Ω



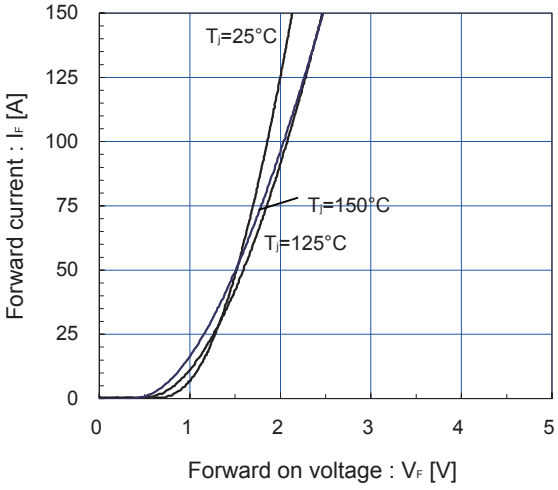
[Inverter]
Switching Loss vs. gate resistance (typ.)
V_{CC}=600V, I_C=75A, V_{GE}=±15V



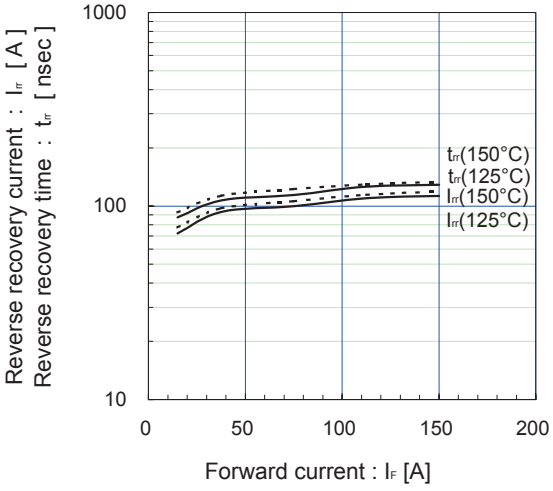
[Inverter]
Reverse bias safe operating area (max.)
+V_{GE}=15V,-V_{GE} <= 15V, R_G >= 2.2Ω ,T_j =150°C



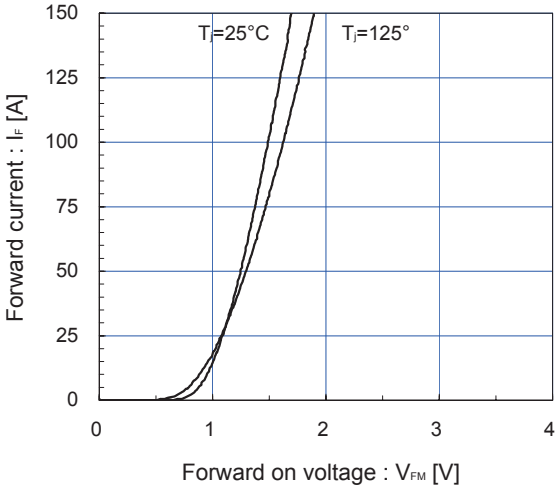
[Inverter]
Forward current vs. forward on voltage (typ.)
chip



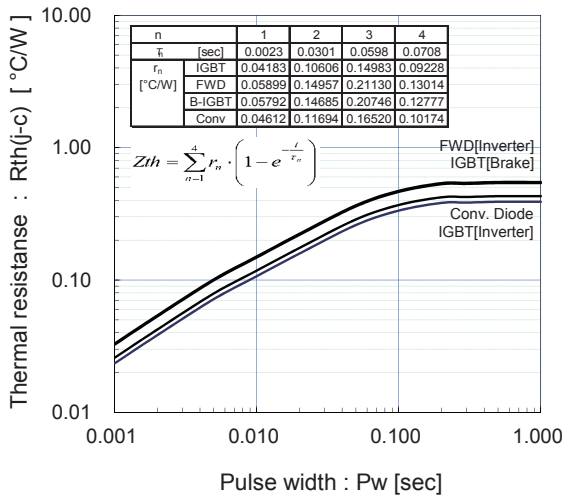
[Inverter]
Reverse recovery characteristics (typ.)
V_{CC}=600V, V_{GE}=±15V, R_G=2.2Ω



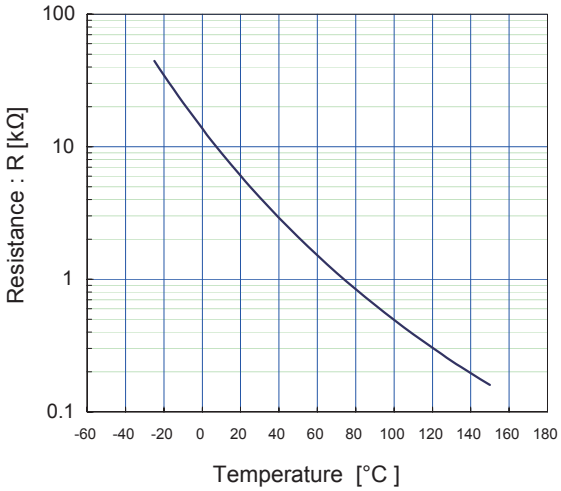
[Converter]
Forward current vs. forward on voltage (typ.)
chip



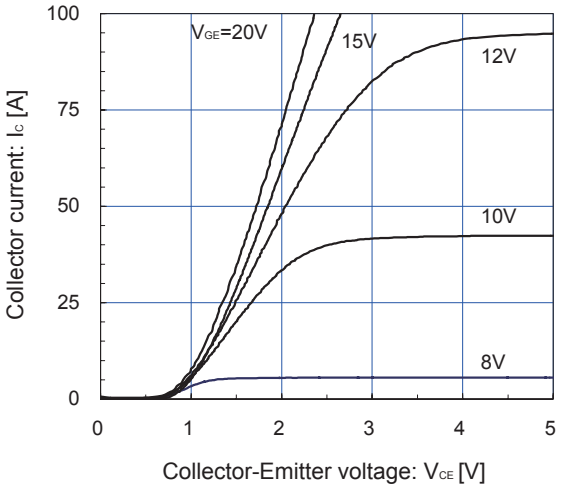
Transient thermal resistance (max.)



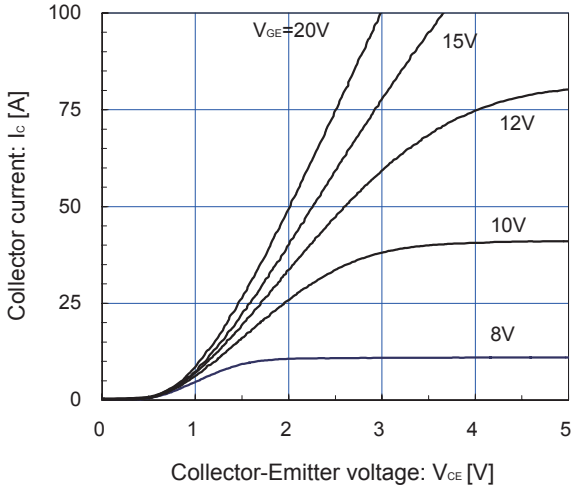
[Thermistor]
Temperature characteristic (typ.)



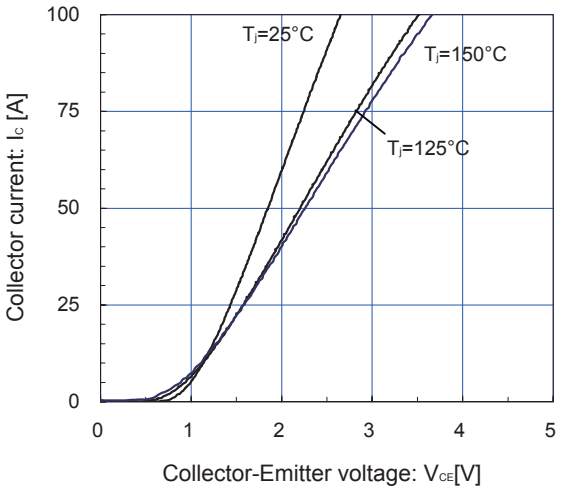
[Brake]
Collector current vs. Collector-Emitter voltage (typ.)
T_j= 25°C / chip



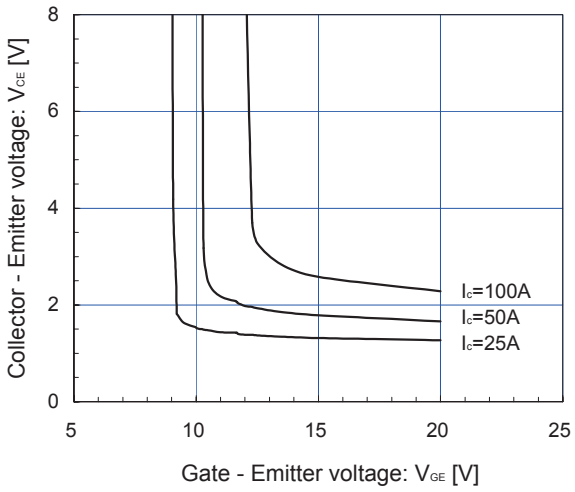
[Brake]
Collector current vs. Collector-Emitter voltage (typ.)
T_j= 150°C / chip



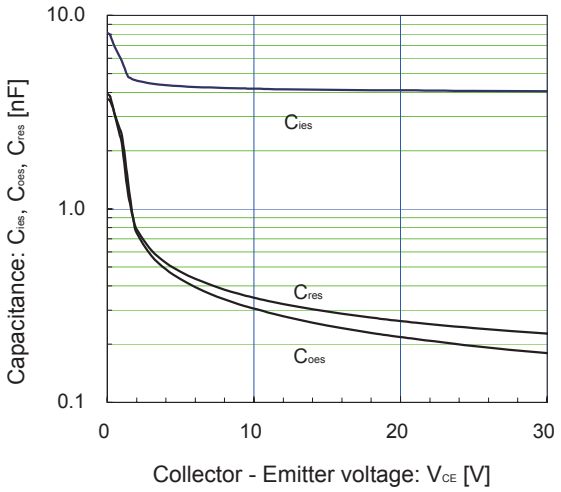
[Brake]
Collector current vs. Collector-Emitter voltage (typ.)
V_{GE}=15V / chip



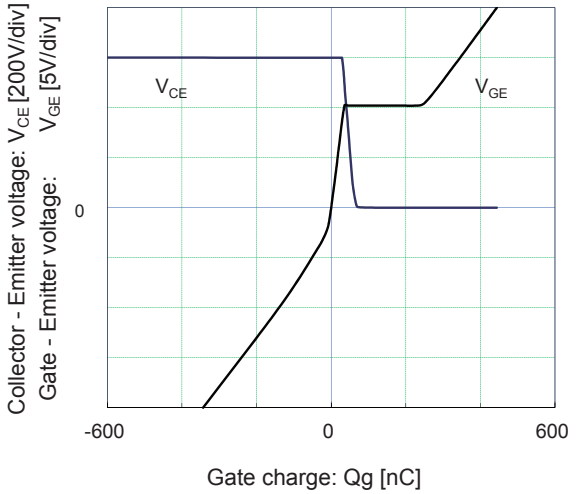
[Brake]
Collector-Emitter voltage vs. Gate-Emitter voltage (typ.)
T_j= 25°C / chip



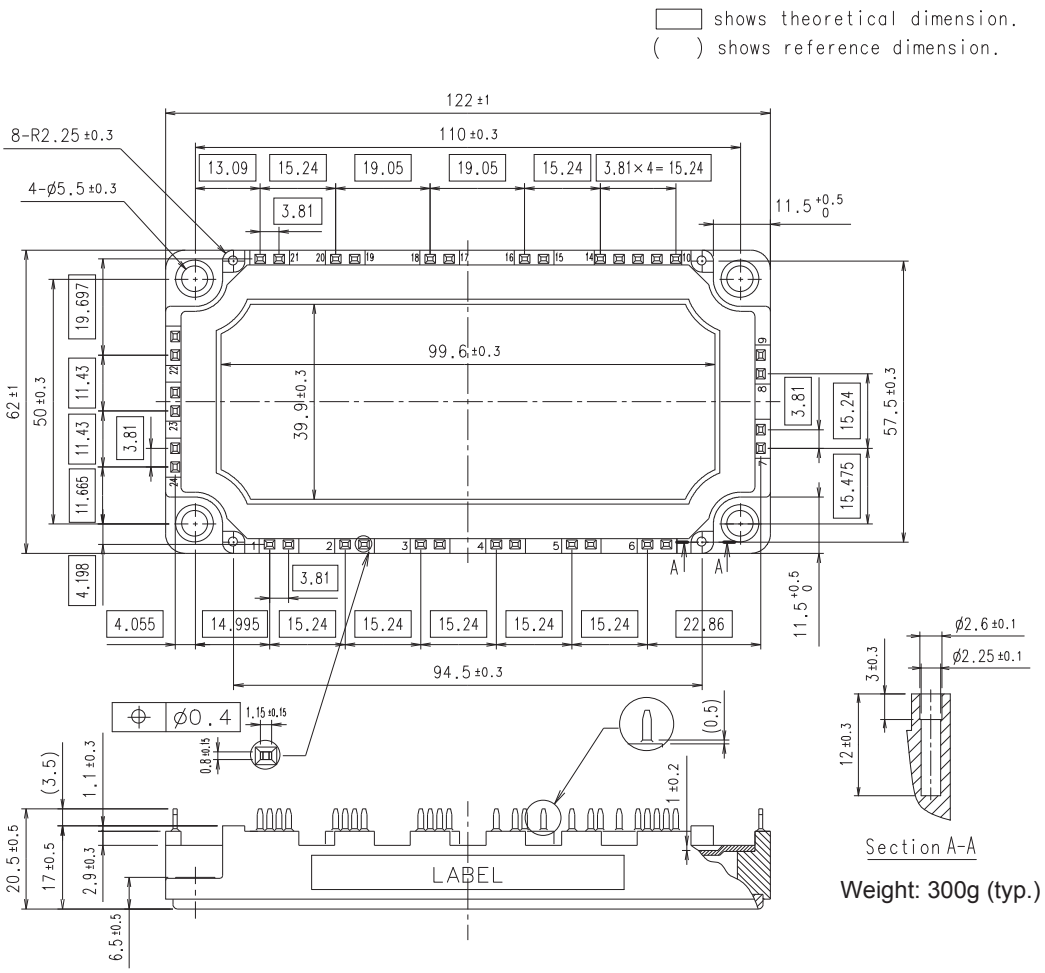
[Brake]
Capacitance vs. Collector-Emitter voltage (typ.)
V_{GE}=0V, f= 1MHz, T_j= 25°C



[Brake]
Dynamic gate charge (typ.)
Vcc=600V, Ic=50A, Tj= 25°C

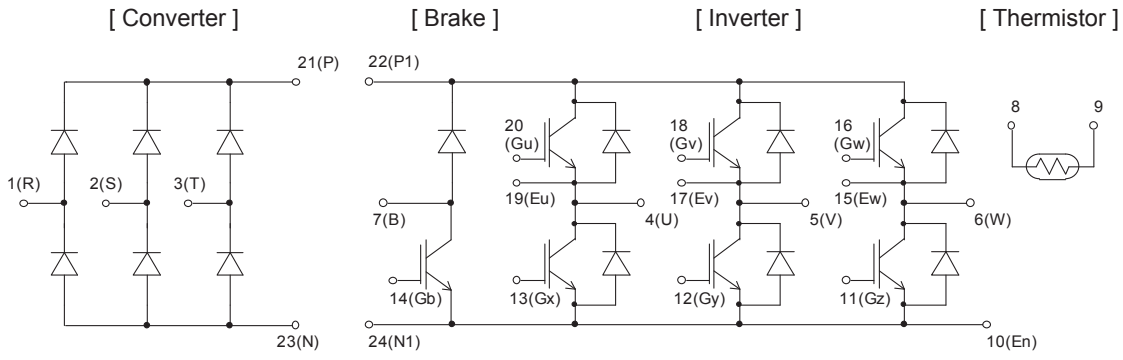


■ Outline Drawings (Unit: mm)



Weight: 300g (typ.)

■ Equivalent Circuit



WARNING

1. This Catalog contains the product specifications, characteristics, data, materials, and structures as of March 2014. The contents are subject to change without notice for specification changes or other reasons. When using a product listed in this Catalog, be sure to obtain the latest specifications.

2. All applications described in this Catalog exemplify the use of Fuji's products for your reference only. No right or license, either express or implied, under any patent, copyright, trade secret or other intellectual property right owned by Fuji Electric Device Technology Co., Ltd. is (or shall be deemed) granted. Fuji Electric Device Technology Co., Ltd. makes no representation or warranty, whether express or implied, relating to the infringement or alleged infringement of other's intellectual property rights which may arise from the use of the applications described herein.

3. Although Fuji Electric Device Technology Co., Ltd. is enhancing product quality and reliability, a small percentage of semiconductor products may become faulty. When using Fuji Electric semiconductor products in your equipment, you are requested to take adequate safety measures to prevent the equipment from causing a physical injury, fire, or other problem if any of the products become faulty. It is recommended to make your design fail-safe, flame retardant, and free of malfunction.

4. The products introduced in this Catalog are intended for use in the following electronic and electrical equipment which has normal reliability requirements.
   • Computers • OA equipment • Communications equipment (terminal devices) • Measurement equipment
   • Machine tools • Audiovisual equipment • Electrical home appliances • Personal equipment • Industrial robots etc.

5. If you need to use a product in this Catalog for equipment requiring higher reliability than normal, such as for the equipment listed below, it is imperative to contact Fuji Electric Device Technology Co., Ltd. to obtain prior approval. When using these products for such equipment, take adequate measures such as a backup system to prevent the equipment from malfunctioning even if a Fuji's product incorporated in the equipment becomes faulty.
   • Transportation equipment (mounted on cars and ships) • Trunk communications equipment
   • Traffic-signal control equipment • Gas leakage detectors with an auto-shut-off feature
   • Emergency equipment for responding to disasters and anti-burglary devices • Safety devices
   • Medical equipment

6. Do not use products in this Catalog for the equipment requiring strict reliability such as the following and equivalents to strategic equipment (without limitation).
   • Space equipment • Aeronautic equipment • Nuclear control equipment
   • Submarine repeater equipment

8. If you have any question about any portion in this Catalog, ask Fuji Electric Device Technology Co., Ltd. or its sales agents before using the product.
Neither Fuji Electric Device Technology Co., Ltd. nor its agents shall be liable for any injury caused by any use of the products not in accordance with instructions set forth herein.